Product data sheet





1 Product profile

1.1 General description

Two planar PIN diodes in common anode configuration in an SOT323 small SMD plastic package.

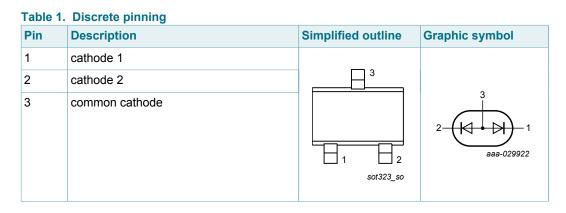
1.2 Features and benefits

- Two elements in common anode configuration in a small SMD plastic package
- · Low diode capacitance
- Low diode forward resistance
- AEC-Q101 qualified

1.3 Applications

General RF applications

2 Pinning information



3 Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BAP51-06W	-	plastic surface-mounted package; 3 leads	SOT323			



4 Marking

Table 3. Marking				
Type number	Marking code	Description		
BAP51-06W	W7%	% = p: made in Hong Kong		
		% = t: made in Malaysia		

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	50	V
I _F	forward current		-	50	mA
P _{tot}	total power dissipation	T _{sp} ≤ 90 °C	-	240	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6 Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		250	K/W

7 Characteristics

Table 6. Characteristics

 T_i = 25 °C unless otherwise specified.

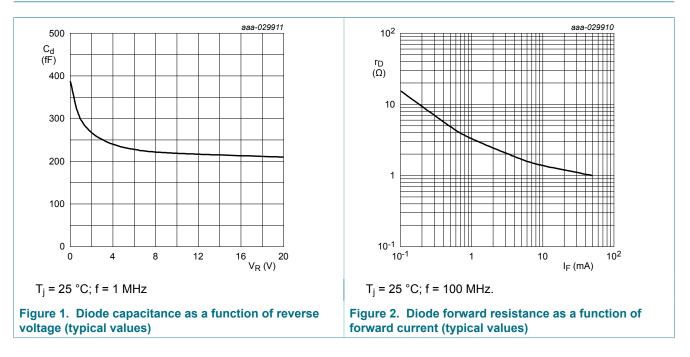
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V _F	forward voltage	I _F = 50 mA	-	0.95	1.1	V	
I _R	reverse current	V _R = 50 V	-	-	100	nA	
C _d	diode capacitance	f = 1 MHz (see <u>Figure 1</u>)					
		V _R = 0 V	-	0.4	-	pF	
		V _R = 1 V	-	0.3	0.55	pF	
		V _R = 5 V	-	0.2	0.35	pF	
r _D	diode forward resistance	f = 100 MHz (see <u>Figure 2</u>)	l				
		I _F = 0.5 mA	[1] -	5.3	9	Ω	
		I _F = 1 mA	[1] -	3.5	6.5	Ω	
		I _F = 10 mA	[1] _	1.5	2.5	Ω	
ISL	isolation	V _R = 0 V (see <u>Figure 4</u>)					
		f = 900 MHz	-	17	-	dB	
		f = 1800 MHz	-	13	-	dB	
		f = 2450 MHz	-	12	-	dB	
L _{ins}	insertion loss	I _F = 0.5 mA (see <u>Figure 3</u>)					
		f = 900 MHz	-	0.44	-	dB	
		f = 1800 MHz	-	0.50	-	dB	
		f = 2450 MHz	-	0.54	-	dB	
		I _F = 1 mA					
		f = 900 MHz	-	0.33	-	dB	
		f = 1800 MHz	-	0.39	-	dB	
		f = 2450 MHz	-	0.43	-	dB	
		I _F = 10 mA					
		f = 900 MHz	-	0.19	-	dB	
		f = 1800 MHz	-	0.24	-	dB	
		f = 2450 MHz	-	0.28	-	dB	
τι	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	-	0.55	-	μs	
Ls	series inductance	I _F = 100 mA; f = 100 MHz		1.6		nH	

[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

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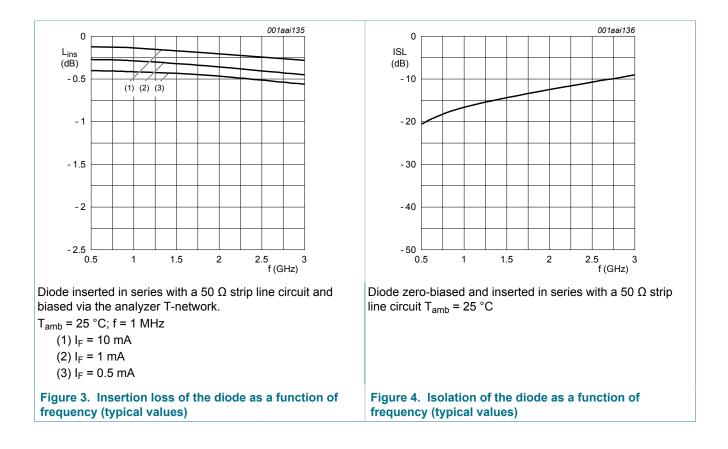
Silicon PIN diode

8 Graphical data



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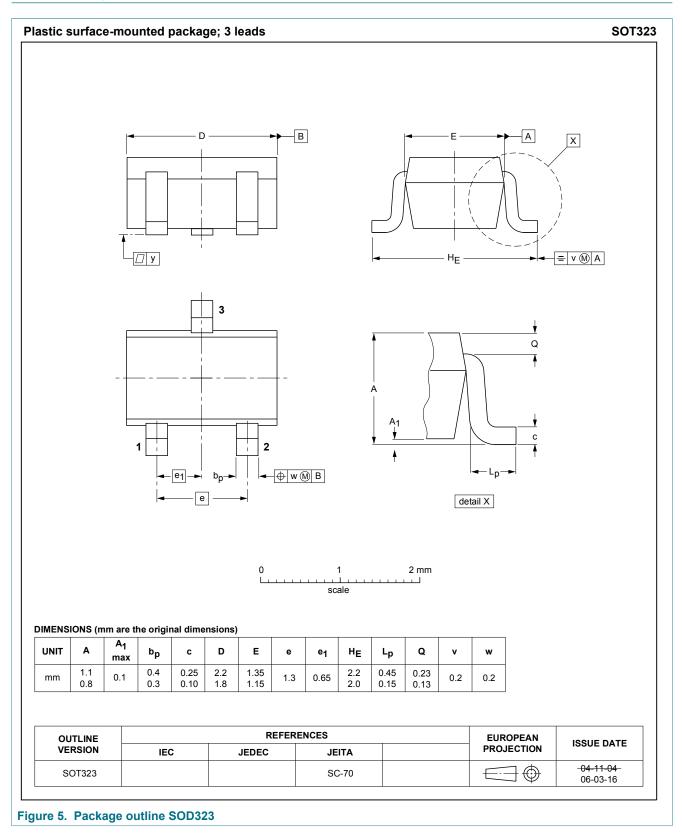


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9 Package outline



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10 Abbreviations

Table 7. Abbreviations				
Acronym	Description			
AQL	acceptable quality level			
PIN	P-type, intrinsic, N-type			
RF	radio frequency			
S4	special inspection level 4			
SMD	surface-mounted device			

11 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP51-06W v.2.1	20190208	Product data sheet	-	BAP51-06W v.2	
Modifications:	aligned the title of the data sheet with the description on the Internet				
BAP51-06W v.2	20181126	Product data sheet	-	BAP51-06W v.1	
Modifications:	 Section 1.2 "Features and benefits" has been updated. The "Legal information" pages have been updated. 				
BAP51-06W v.1	20080526	Product data sheet	-	-	

12 Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

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